

Supporting Information

Zinc Ion Functional Doping for All-Inorganic Planar CsPbIBr₂ Perovskite Solar Cell with Efficiency over 10.5%

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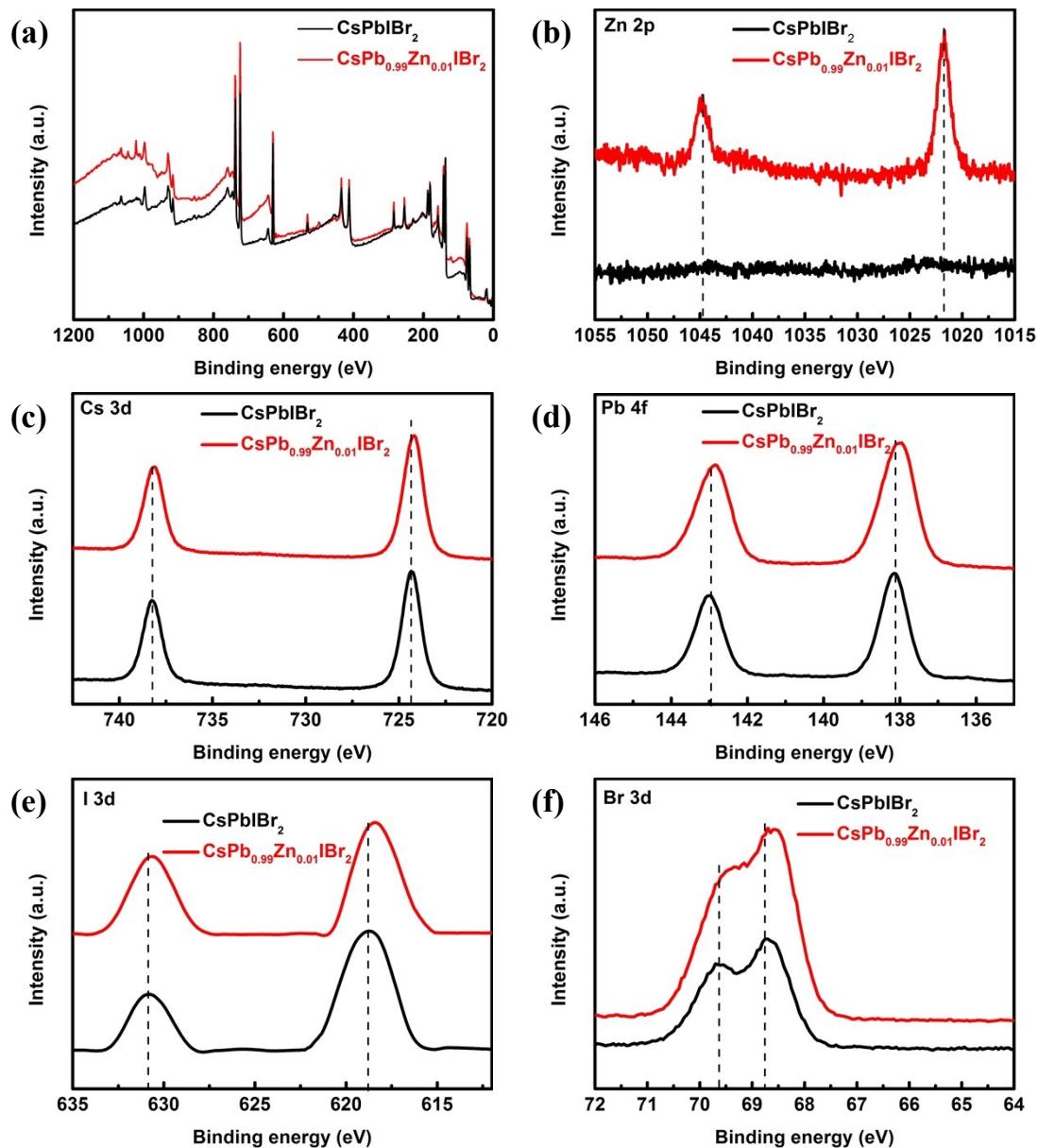


Fig. S1. a) XPS survey spectra of pristine CsPbIBr_2 and $\text{CsPb}_{0.99}\text{Zn}_{0.01}\text{IBr}_2$ films. b) Zn 2p, c) Cs 3d, d) Pb 4f, e) I 3d, and f) Br 3d XPS core spectra of pristine CsPbIBr_2 and $\text{CsPb}_{0.99}\text{Zn}_{0.01}\text{IBr}_2$ films, respectively.

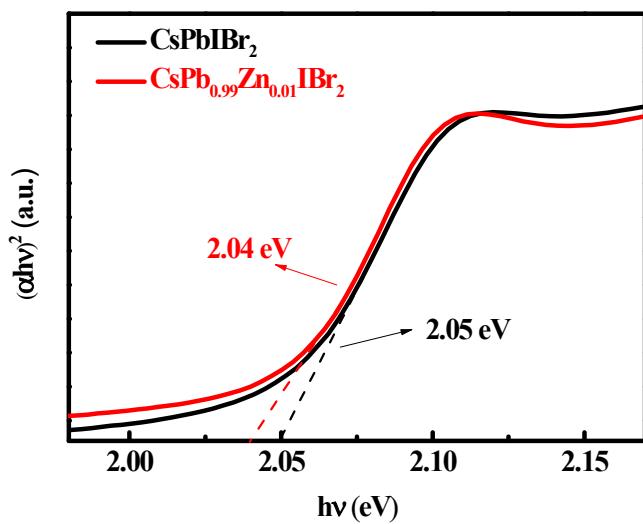


Fig. S2. Tauc plots of perovskite films obtained from UV-vis absorption spectra with equation $(\alpha h\nu)^2 = A(h\nu - E_g)$.

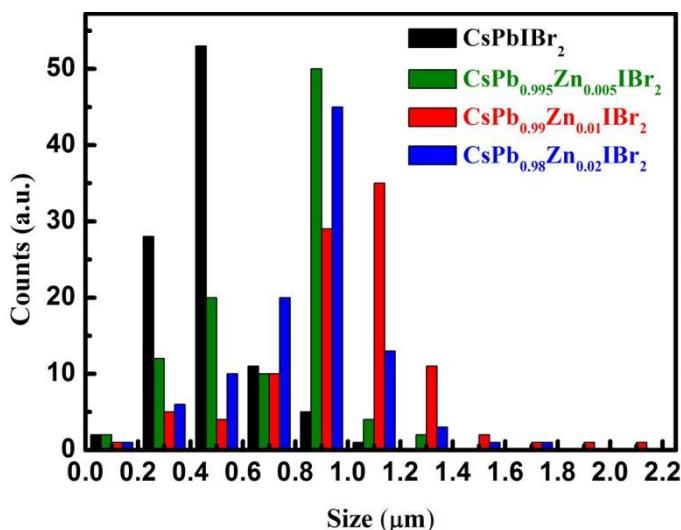


Fig. S3. Grain statistical distribution based on the SEM surface morphology images.

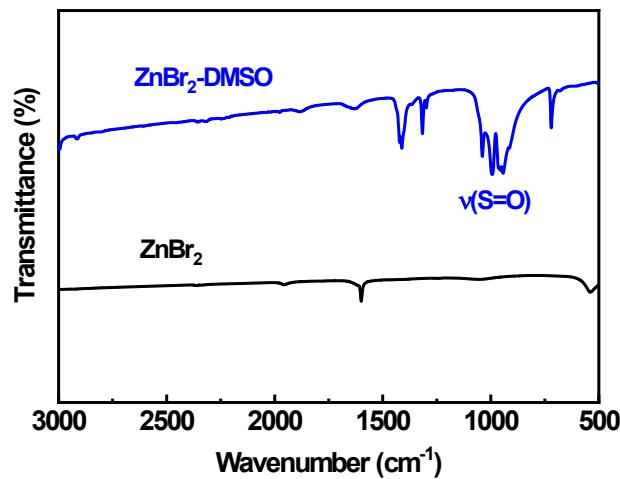


Fig. S4 Fourier transform infrared spectrometer (FTIR) spectra of ZnBr_2 and $\text{ZnBr}_2\text{-DMSO}$ powders.

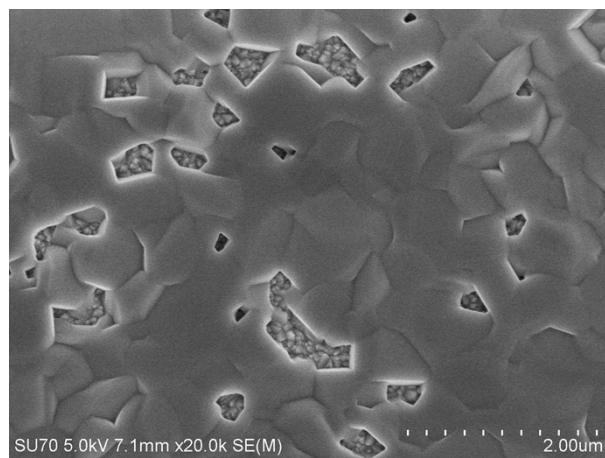


Fig. S5. The scanning electron microscope (SEM) image of the $\text{CsPb}_{0.9}\text{Zn}_{0.1}\text{IBr}_2$ perovskite film.

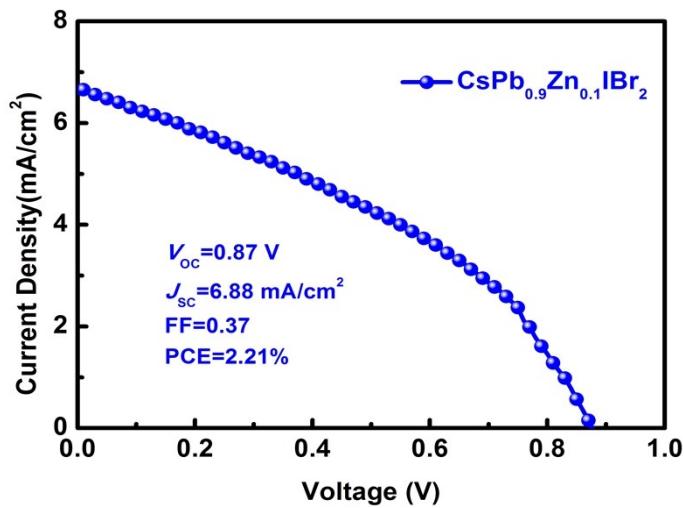


Fig. S6. The J - V curve under RS of the $\text{CsPb}_{0.9}\text{Zn}_{0.1}\text{IBr}_2$ and the corresponding data parameters.

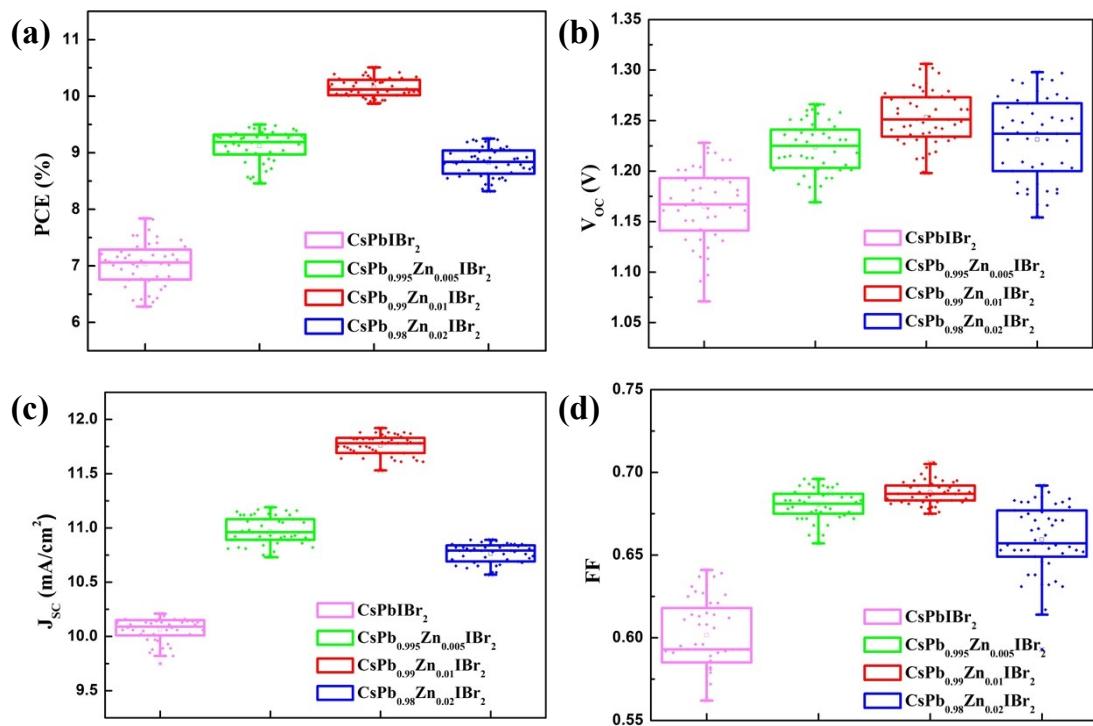


Fig. S7. a) PCE, b) V_{oc} , c) J_{sc} , and d) FF value distributions of CsPbIBr_2 -based PSCs without and with different Zn^{2+} doping.

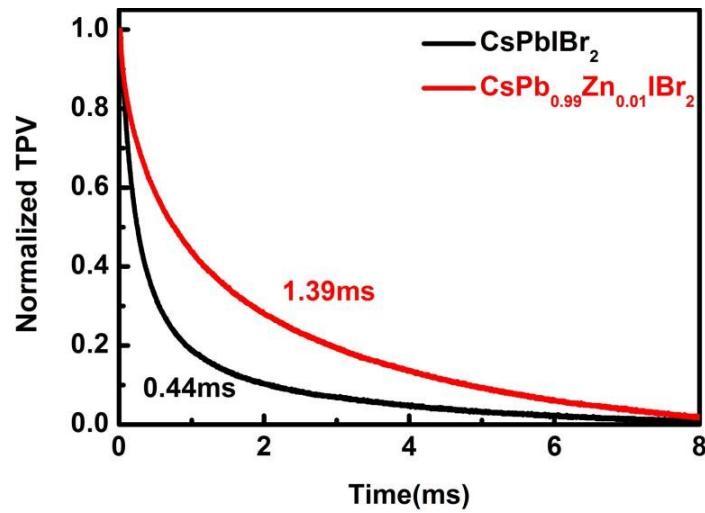


Fig. S8. TPV decay curves of the CsPbIBr_2 and $\text{CsPb}_{0.99}\text{Zn}_{0.01}\text{IBr}_2$ devices.

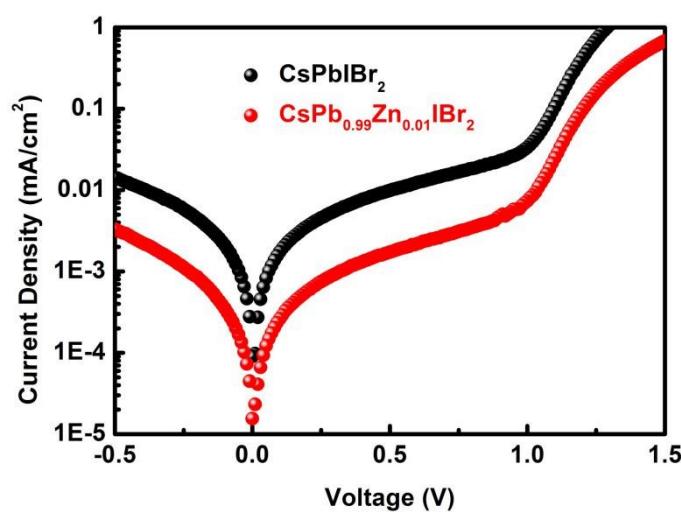


Fig. S9. The dark J - V curves of the CsPbIBr_2 and $\text{CsPb}_{0.99}\text{Zn}_{0.01}\text{IBr}_2$ devices.

Table S1. Photovoltaic parameters of CsPbIBr₂ and CsPb_{0.99}Zn_{0.01}IBr₂ PSCs.

Device	Scan direction	V _{oc} (V)	J _{sc} (mA/cm ²)	FF	PCE (%)	HI(%)
CsPbIBr ₂	FS	1.15	8.98	0.61	6.29	19.77
	RS	1.22	10.21	0.63	7.84	
CsPb _{0.99} Zn _{0.01} IBr ₂	FS	1.25	11.49	0.65	9.34	11.13
	RS	1.28	11.92	0.69	10.51	

Table S2. The fitted parameters of carrier lifetimes based on CsPbIBr₂ and CsPb_{0.99}Zn_{0.01}IBr₂ PSCs.

device	A ₁	τ ₁ (ns)	A ₂	τ ₂ (ns)	τ _{ave} (ns)
CsPbIBr ₂	84.17	1.98	15.83	11.33	2.27
CsPb _{0.99} Zn _{0.01} IBr ₂	60.36	4.82	39.64	12.59	6.37